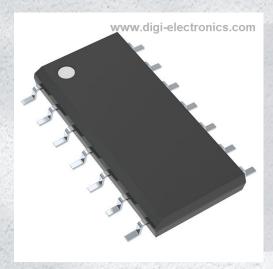


MC74AC08DR2G Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number MC74AC08DR2G-DG

Manufacturer onsemi

Manufacturer Product Number MC74AC08DR2G

Description IC GATE AND 4CH 2-INP 14SOIC

Detailed Description AND Gate IC 4 Channel 14-SOIC



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MC74AC08DR2G	onsemi
Series:	Product Status:
74AC	Active
Logic Type:	Number of Circuits:
AND Gate	4
Number of Inputs:	Features:
2	
Voltage - Supply:	Current - Quiescent (Max):
2V ~ 6V	4 μΑ
Current - Output High, Low:	Input Logic Level - Low:
24mA, 24mA	0.9V ~ 1.65V
Input Logic Level - High:	Max Propagation Delay @ V, Max CL:
2.1V ~ 3.85V	7.5ns @ 5V, 50pF
Operating Temperature:	Mounting Type:
-40°C ~ 85°C	Surface Mount
Supplier Device Package:	Package / Case:
14-SOIC	14-SOIC (0.154", 3.90mm Width)
Base Product Number:	
74AC08	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

8542.39.0001

MARKING



www.onsemi.com

Quad 2-Input AND Gate

High-Performance Silicon-Gate CMOS

MC74AC08, MC74ACT08

Features

- Outputs Source/Sink 24 mA
- 'ACT08 Has TTL Compatible Inputs
- -Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

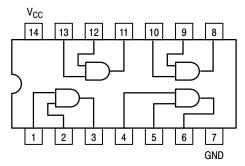


Figure 1. Pinout: 14-Lead Packages Conductors (Top View)

DIAGRAMS

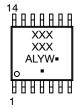


SOIC-14 **D SUFFIX** CASE 751A





TSSOP-14 **DT SUFFIX CASE 948G**



XXX = Specific Device Code = Assembly Location

WL or L = Wafer Lot = Year WW or W = Work Week G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +6.5	V
VI	DC Input Voltage	$-0.5 \le V_{I} \le V_{CC} + 0.5$	V
Vo	DC Output Voltage (Note 1)	$-0.5 \le V_{O} \le V_{CC} + 0.5$	V
I _{IK}	DC Input Diode Current	±20	mA
I _{OK}	DC Output Diode Current	±50	mA
Io	DC Output Sink/Source Current	±50	mA
I _{CC}	DC Supply Current per Output Pin	±50	mA
I _{GND}	DC Ground Current per Output Pin	±50	mA
T _{STG}	Storage Temperature Range	- 65 to +150	°C
TL	Lead temperature, 1 mm from Case for 10 Seconds	260	°C
TJ	Junction temperature under Bias	+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2) SOIC TSSOP		°C/W
P _D	Power Dissipation in Still Air at 25°C SOIC TSSOP		mW
MSL	Moisture Sensitivity	Level 1	
F _R	Flammability Rating Oxygen Index: 30% – 35%	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage Human Body Model (Note 3) Charged Device Model (Note 4)		V
I _{Latch-Up}	Latch-Up Performance Above V _{CC} and Below GND at 85°C (Note 5)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. IO absolute maximum rating must be observed.
- The package thermal impedance is calculated in accordance with JESD51–7.
 Tested to EIA/JESD22–A114–A.
- 4. Tested to JESD22-C101-A.
- 5. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Тур	Max	Unit
.,	O and Wellings	'AC	2.0	5.0	6.0	.,
V _{CC}	Supply Voltage	'ACT	4.5	5.0	5.5	V
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Ref. to GND)		0	-	V _{CC}	V
		V _{CC} @ 3.0 V	-	150	-	ns/V
† †,	Input Rise and Fall Time (Note 1) 'AC Devices except Schmitt Inputs	V _{CC} @ 4.5 V	-	40	-	1
		V _{CC} @ 5.5 V	-	25	_	1
	Input Rise and Fall Time (Note 2)	V _{CC} @ 4.5 V	-	10	_	0.4
t _r , t _f	'ACT Devices except Schmitt Inputs	V _{CC} @ 5.5 V	-	8.0	_	ns/V
T _A	Operating Ambient Temperature Range		-40	25	85	°C
I _{OH}	Output Current – High		-	_	-24	mA
I _{OL}	Output Current – Low		-	-	24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. V_{in} from 30% to 70% V_{CC}; see individual Data Sheets for devices that differ from the typical input rise and fall times.

2. V_{in} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

DC CHARACTERISTICS

				74	AC	74AC	
			V _{CC}	T _A = -	⊦25°C	T _A = -40°C to +85°C	
Symbol	Parameter	Conditions	(V)	Тур	Guar	anteed Limits	Unit
V _{IH}	Minimum High Level Input Voltage	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	V
V _{IL}	Maximum Low Level Input Voltage	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V
V _{OH}	Minimum High Level Output Voltage	Ι _{ΟUT} = –50 μΑ	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V
		$V_{IN} = V_{IL}$ or V_{IH} (Note 3) -12 m $I_{OH} \qquad -24 \text{ m}$ -24 m	A 4.5	- - -	2.56 3.86 4.86	2.46 3.76 4.76	V
V _{OL}	Minimum Low Level Output Voltage	Ι _{ΟUT} = 50 μΑ	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V
		V _{IN} = V _{IL} or V _{IH} (Note 3) 12 mA I _{OL} 24 mA 24 mA	4.5	- - -	0.36 0.36 0.36	0.44 0.44 0.44	V
I _{IN}	Maximum Input Leakage Current	V _I = V _{CC} , GND	5.5	-	±0.1	±1.0	μΑ
I _{OLD}	Minimum Dynamic (Note 4)	V _{OLD} = 1.65 V Max	5.5	-	-	75	mA
I _{OHD}	Output Current	V _{OHD} = 3.85 V Min	5.5	-	-	-75	mA
Icc	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND	5.5	-	4.0	40	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NOTE: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC} .

3. All outputs loaded; thresholds on input associated with output under test.

- 4. Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS

			74AC		74AC			
		V _{CC} (V)		գ = +25° L = 50 p		T _A = - to +8 C _L = 8	35°C	
Symbol	Parameter	(Note5)	Min	Тур	Max	Min	Max	Unit
t _{PLH}	Propagation Delay	3.3 5.0	1.5 1.5	7.5 5.5	9.5 7.5	1.0 1.0	10.0 8.5	ns
t _{PHL}	Propagation Delay	3.3 5.0	1.5 1.5	7.0 5.5	8.5 7.0	1.0 1.0	9.0 7.5	ns

^{5.} Voltage Range 3.3 V is 3.3 V ± 0.3 V. Voltage Range 5.0 V is 5.0 V ±0.5 V.

DC CHARACTERISTICS

					74	CT	74ACT		
				V _{CC}	T _A =	+25°C	T _A = -40°C to +85°C		
Symbol	Parameter	Conditio	ns	(V)	Тур	Guar	anteed Limits	Unit	
V _{IH}	Minimum High Level	V _{OUT} = 0.1 V		4.5	1.5	2.0	2.0	V	
	Input Voltage	or V _{CC} – 0.1 V		5.5	1.5	2.0	2.0	V	
V _{IL}	Maximum Low Level	V _{OUT} = 0.1 V		4.5	1.5	0.8	0.8	V	
	Input Voltage	or V _{CC} – 0.1 V		5.5	1.5	0.8	0.8	V	
V _{OH}	Minimum High Level	I _{OUT} = -50 μA		4.5	4.49	4.4	4.4	V	
	Output Voltage			5.5	5.49	5.4	5.4	l v	
		$V_{IN} = V_{IL}$ or V_{IH} (N	ote 6)					V	
			-24 mA	4.5	-	3.86	3.76		
			-24 mA	5.5	-	4.86	4.76		
V _{OL}	Maximum Low Level	I _{OUT} = 50 μA		4.5	0.001	0.1	0.1	V	
	Output Voltage			5.5	0.001	0.1	0.1	V	
		$V_{IN} = V_{IL}$ or V_{IH} (N	ote 6)					V	
			24 mA	4.5	-	0.36	0.44		
			24 mA	5.5	-	0.36	0.44		
I _{IN}	Maximum Input Leakage Current	V _I = V _{CC} , GND		5.5	-	±0.1	±1.0	μΑ	
ΔI_{CCT}	Additional Max. I _{CC} /Input	V _I = V _{CC} - 2.1 V		5.5	0.6	_	1.5	mA	
I _{OLD}	Minimum Dynamic (Note 7)	V _{OLD} = 1.65 V Max	·	5.5	-	_	75	mA	
I _{OHD}	Output Current	V _{OHD} = 3.85 V Mir	1	5.5	-	_	-75	mA	
I _{CC}	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND		5.5	-	4.0	40	μΑ	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC CHARACTERISTICS

			74ACT		74ACT			
			_		,	T _A = -		
		V 00	T _A = +25°C C _L = 50 pF		to +85°C C _L = 50 pF			
Symbol	Parameter	V _{CC} (V) (Note 8)	Min	Тур	Max	Min	Max	Unit
t _{PLH}	Propagation Delay	5.0	1.0	-	9.0	1.0	10.0	ns
t _{PHL}	Propagation Delay	5.0	1.0	-	9.0	1.0	10.0	ns

^{8.} Voltage Range 5.0 V is 5.0 V \pm 0.5 V.

CAPACITANCE

Symbol	Parameter	Test Conditions	Value Typ	Unit
C _{IN}	Input Capacitance	V _{CC} = 5.0 V	4.5	pF
C _{PD}	Power Dissipation Capacitance	V _{CC} = 5.0 V	20	pF

^{6.} All outputs loaded; thresholds on input associated with output under test.

^{7.} Maximum test duration 2.0 ms, one output loaded at a time.

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MC74AC08DG	AC08	SOIC-14 (Pb-Free)	55 Units / Rail
MC74AC08DR2G	AC08	SOIC-14 (Pb-Free)	2500 / Tape & Reel
MC74AC08DR2G-Q*	AC08	SOIC-14 (Pb-Free)	2500 / Tape & Reel
MC74AC08DTR2G	AC 08	TSSOP-14 (Pb-Free)	2500 / Tape & Reel
MC74ACT08DG	ACT08	SOIC-14 (Pb-Free)	55 Units / Rail
MC74ACT08DR2G	ACT08	SOIC-14 (Pb-Free)	2500 / Tape & Reel
MC74ACT08DTR2G	ACT 08	TSSOP-14 (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP

Capable.



MECHANICAL CASE OUTLINE

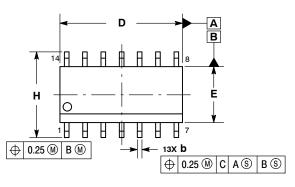
PACKAGE DIMENSIONS

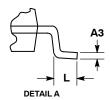


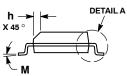
△ 0.10

SOIC-14 NB CASE 751A-03 ISSUE L

DATE 03 FEB 2016





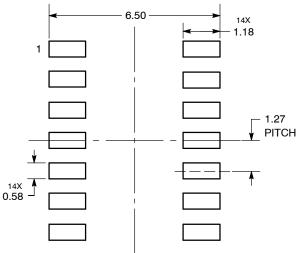




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
 - ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT
- MAXIMUM MATERIAL CONDITION.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
- 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.35	1.75	0.054	0.068	
A1	0.10	0.25	0.004	0.010	
АЗ	0.19	0.25	0.008	0.010	
b	0.35	0.49	0.014	0.019	
D	8.55	8.75	0.337	0.344	
Е	3.80	4.00	0.150	0.157	
е	1.27 BSC		0.050	BSC	
Η	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.019	
L	0.40	1.25	0.016	0.049	
М	0 °	7°	0 °	7°	

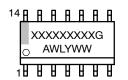
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

C SEATING PLANE

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code Α = Assembly Location

WL = Wafer Lot Υ = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SOIC-14 CASE 751A-03 ISSUE L

DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

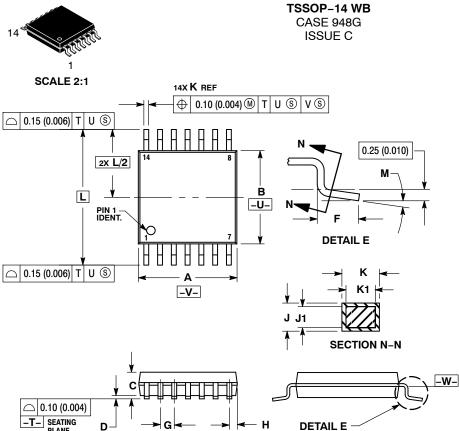
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DESCRIPTION:	SOIC-14 NB		PAGE 2 OF 2	

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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



DATE 17 FEB 2016

- NOTES.

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

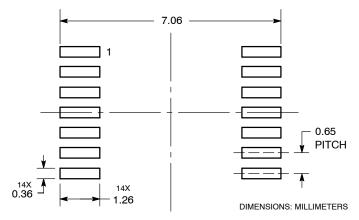
 3. DIMENSION A DOES NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE
- INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
- INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

 6. TERMINAL NUMBERS ARE SHOWN FOR DEFERENCE ONLY
- REFERENCE ONLY.
 DIMENSION A AND B ARE TO BE
- DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
Н	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
М	o °	8 °	o °	a °

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



= Assembly Location

= Wafer Lot = Year = Work Week W

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

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